

DMP2900UW-7 Datasheet

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DMP2900UW-7-DG
Diodes Incorporated
DMP2900UW-7
MOSFET BVDSS: 8V-24V SOT323
P-Channel 20 V 600mA (Ta) 300mW Surface Mount SOT-323

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DMP2900UW-7	Diodes Incorporated
Series:	Product Status:
	Active
FET Type:	Technology:
P-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (ld) @ 25°C:
20 V	600mA (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
1.8V, 4.5V	750mOhm @ 430mA, 4.5V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
1V @ 250μΑ	0.7 nC @ 4.5 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±6V	49 pF @ 16 V
FET Feature:	Power Dissipation (Max):
-	300mW
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
SOT-323	SC-70, SOT-323
Base Product Number:	
DMP2900	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	





DMP2900UW

Product Summary

BV _{DSS}	Rds(on)	ID TA = +25°C
	750mΩ @ V _{GS} = -4.5V	-0.6A
-20V	1050mΩ @ V _{GS} = -2.5V	-0.5A
	1500mΩ @ V _{GS} = -1.8V	-0.45A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

- DC-DC Converters
- Load Switch
- Power Management Functions



Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

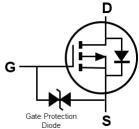
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed Over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)



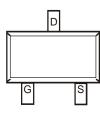


SOT323

Top View



Equivalent Circuit



Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2900UW-7	SOT323	3,000/Tape & Reel
DMP2900UW-13	SOT323	10,000/Tape & Reel

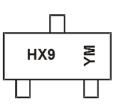
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



HX9 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Date Code Rey												
Year	2018		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	F		_	J	K	L	М	Ν	0	Р	R	s
	r											
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	Vdss	-20	V
Gate-Source Voltage	V _{GSS}	±6	V
Continuous Drain Current (Note 6) V_{GS} = -4.5V	lo	-0.6 -0.5	А
Maximum Body Diode Forward Current (Note 6)	ls	-0.45	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	Ідм	-2.5	A

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	393	°C/W
Total Power Dissipation (Note 6)		PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Rəja	272	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 7)	OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV _{DSS}	-20	—	—	V	$V_{GS} = 0V, I_D = -250 \mu A$			
Zero Gate Voltage Drain Current TJ = +25°C	IDSS		_	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$			
Gate-Source Leakage	I _{GSS}		—	±2.0	μA	$V_{GS} = \pm 4.5 V$, $V_{DS} = 0 V$			
ON CHARACTERISTICS (Note 7)									
Gate Threshold Voltage	VGS(TH)	-0.5	—	-1.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$			
				0.75		$V_{GS} = -4.5V, I_{D} = -430mA$			
Static Drain-Source On-Resistance	RDS(ON)	—	— 1.05	Ω	V _{GS} = -2.5V, I _D = -300mA				
				1.5		V _{GS} = -1.8V, I _D = -150mA			
Diode Forward Voltage	V _{SD}	_		-1.2	V	$V_{GS} = 0V, I_{S} = -150mA$			
DYNAMIC CHARACTERISTICS (Note 8)						-			
Input Capacitance	Ciss		49		pF				
Output Capacitance	Coss		12	—	pF	V _{DS} = -16V, V _{GS} = 0V, f = 1.0MHz			
Reverse Transfer Capacitance	Crss	—	3.4	_	pF	1 = 1.00012			
Total Gate Charge	Qg	_	0.7	—	nC				
Gate-Source Charge	Qgs	_	0.1		nC	Vgs = -4.5V, Vds = -10V, - In = -250mA			
Gate-Drain Charge	Q _{gd}		0.1		nC	-1D = -250 mA			
Turn-On Delay Time	tD(ON)		16		ns				
Turn-On Rise Time	tR		15		ns	$V_{DD} = -10V, V_{GS} = -4.5V,$			
Turn-Off Delay Time	tD(OFF)		213	—	ns	R _L = 47Ω, R _G = 10Ω, I _D = -200mA			
Turn-Off Fall Time	tF	_	89		ns	-20011A			
Reverse Recovery Time	t _{RR}	_	10.5		ns	I _F = -1.0A, di/dt = 100A/µs			
Reverse Recovery Charge	Q_{RR}	-	1.8	—	nC	$r_{\rm F} = -1.0$ A, u/ul – 100 A/µs			

 Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:



DMP2900UW

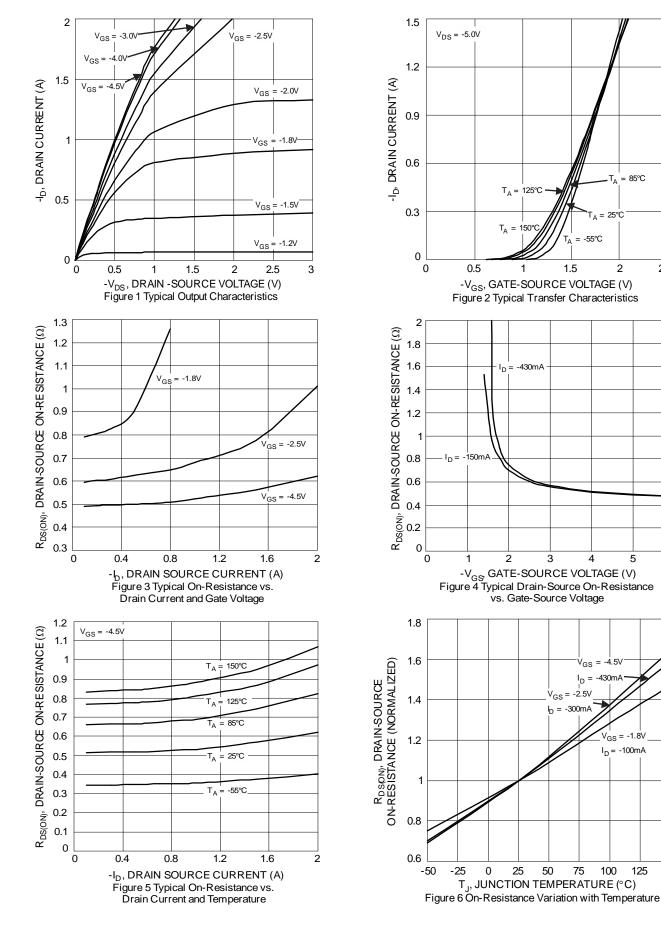
= 85°C

2

5

6

2.5

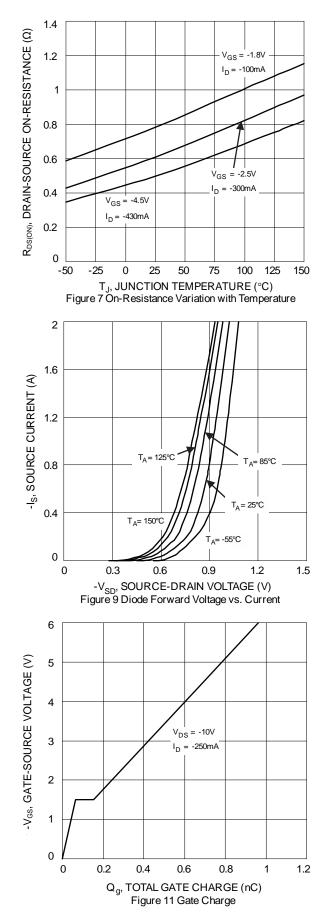


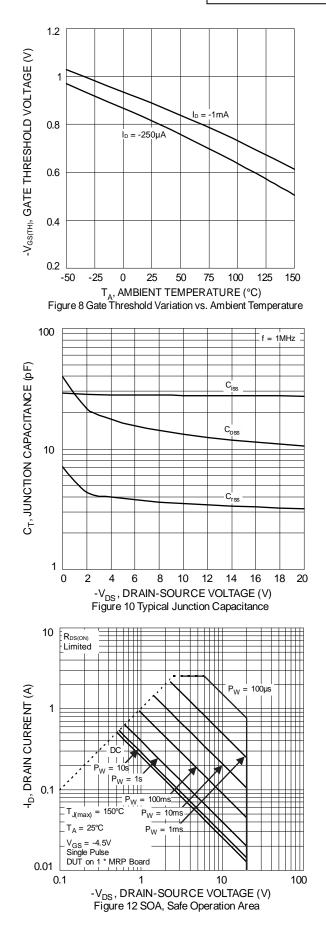
150

125



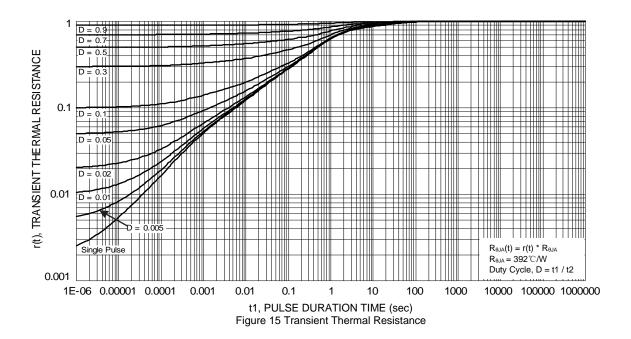
DMP2900UW





DMP2900UW Document number: DS41296 Rev. 5 - 2

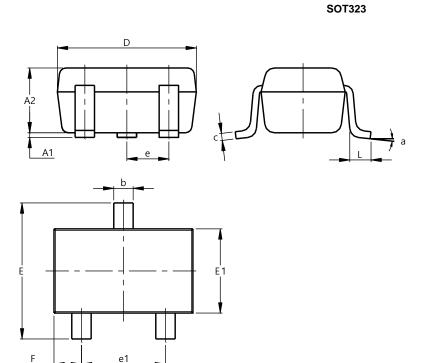






Package Outline Dimensions

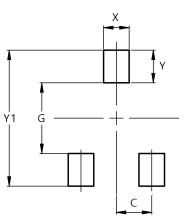
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SC	T323	
Dim	Min	Max	Тур
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.25	0.40	0.30
С	0.10	0.18	0.11
D	1.80	2.20	2.15
Е	2.00	2.20	2.10
E1	1.15	1.35	1.30
е	C).650 B	SC
e1	1.20	1.40	1.30
F	0.375	0.475	0.425
L	0.25	0.40	0.30
а	0°	8°	
All	Dimen	sions	in mm

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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